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ATP101

P-Channel Power MOSFET -30V, -25A, 30mΩ, Single ATPAK

Features

- Low ON-resistance
- Slim package
- Halogen free compliance
- Large current
- 4.5V drive
- Protection diode in

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-30	V
Gate-to-Source Voltage	V _{GSS}		±20	V
Drain Current (DC)	I _D		-25	A
Drain Current (PW≤10μs)	I _{DP}	PW≤10μs, duty cycle≤1%	-75	A
Allowable Power Dissipation	P _D	T _c =25°C	30	W
Channel Temperature	T _{ch}		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C
Avalanche Energy (Single Pulse) *1	E _{AS}		25	mJ
Avalanche Current *2	I _{AV}		-13	A

Note : *1 V_{DD}=-10V, L=200μH, I_{AV}=-13A

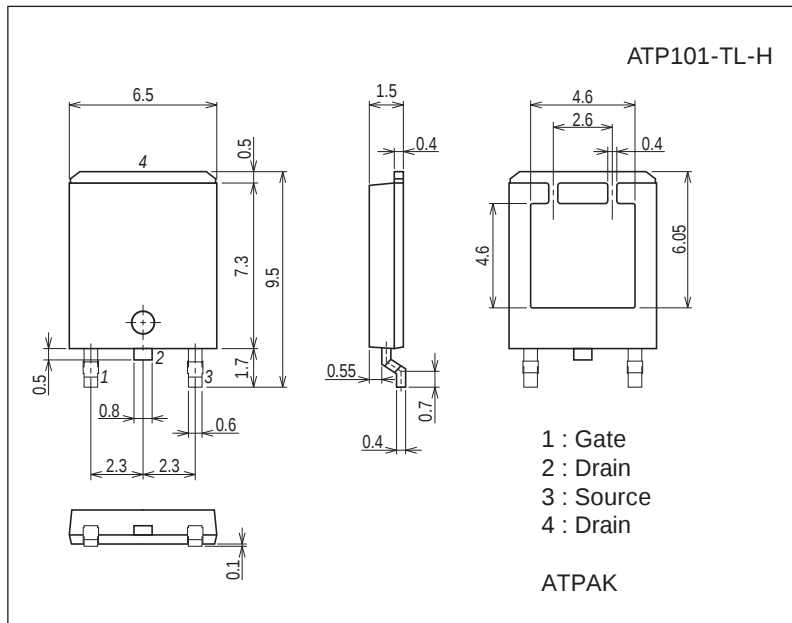
*2 L≤200μH, Single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

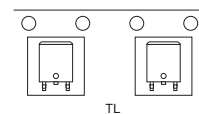
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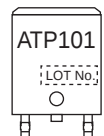
Product & Package Information

- Package : ATPAK
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

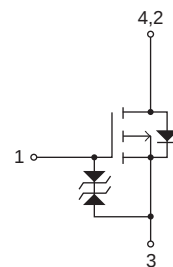
Packing Type: TL



Marking



Electrical Connection

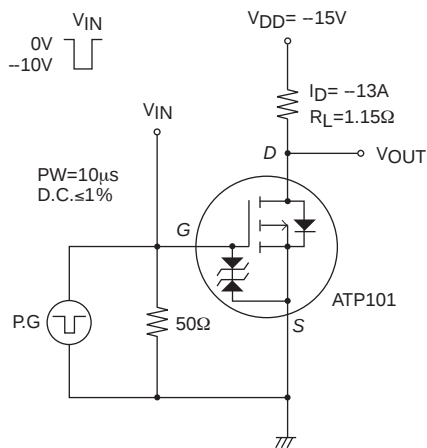


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Electrical Characteristics at Ta=25°C

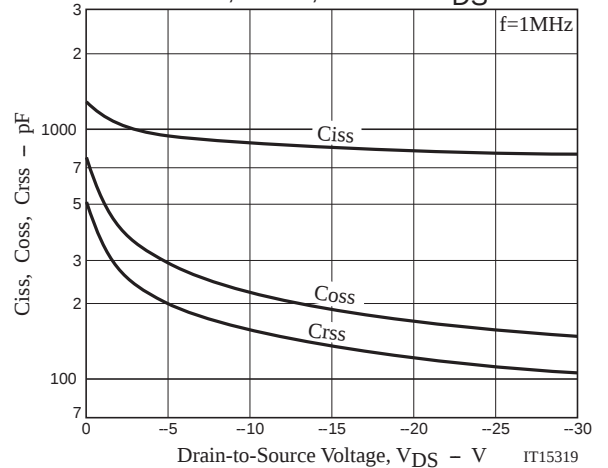
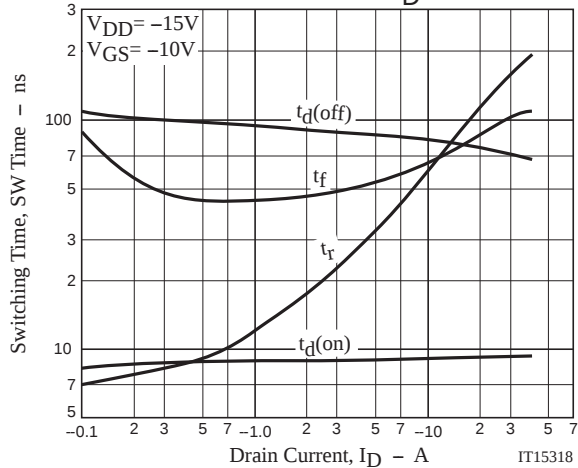
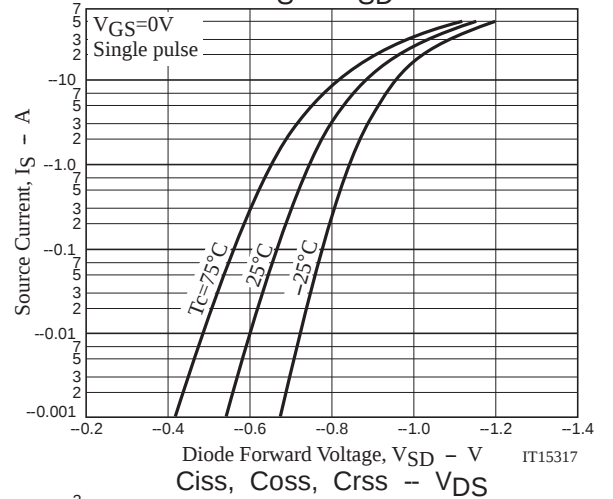
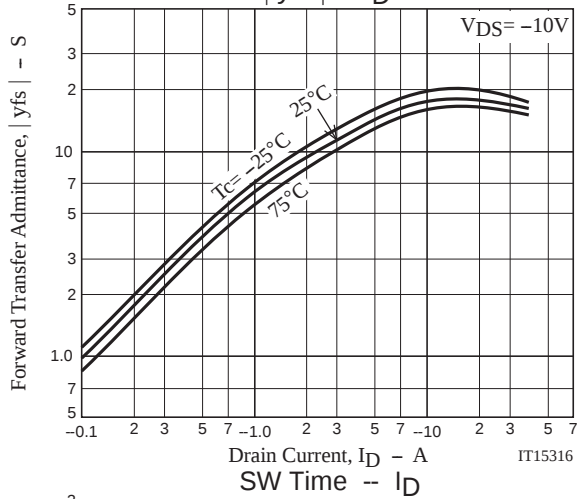
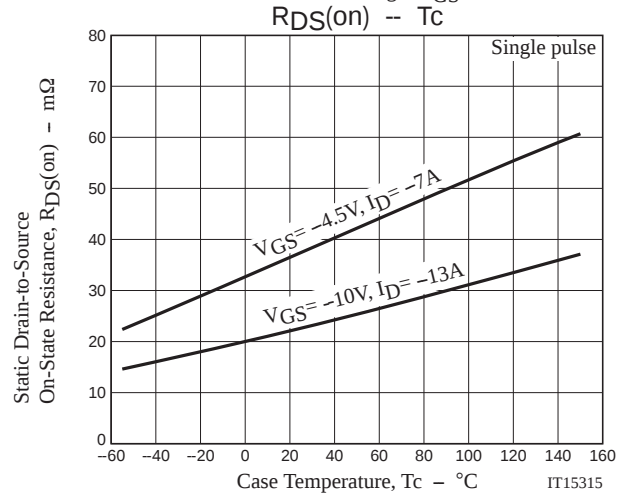
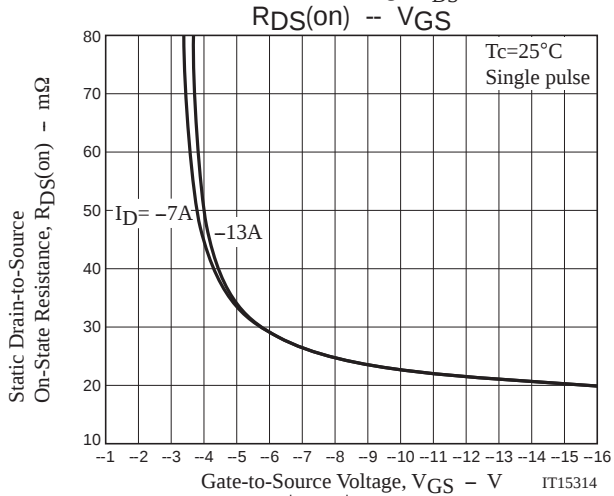
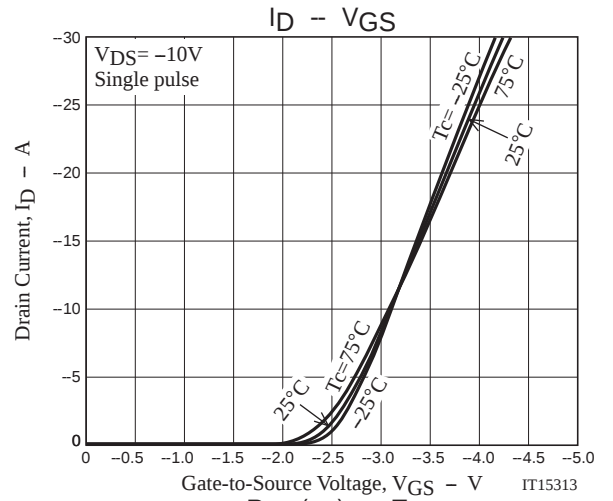
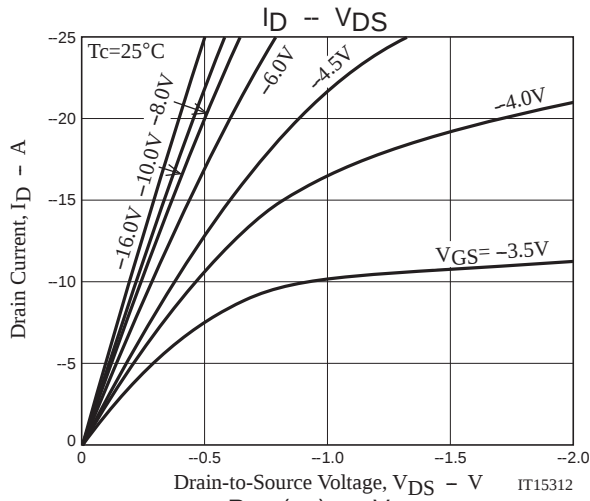
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D = -1mA, V_{GS} = 0V$	-30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -30V, V_{GS} = 0V$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS} = \pm 16V, V_{DS} = 0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS} = -10V, I_D = -1mA$	-1.2		-2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = -10V, I_D = -13A$		17		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D = -13A, V_{GS} = -10V$		23	30	m Ω
	$R_{DS(on)2}$	$I_D = -7A, V_{GS} = -4.5V$		36	51	m Ω
Input Capacitance	C_{iss}	$V_{DS} = -10V, f = 1MHz$		875		pF
Output Capacitance	C_{oss}			220		pF
Reverse Transfer Capacitance	C_{rss}			155		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		9.2		ns
Rise Time	t_r			70		ns
Turn-OFF Delay Time	$t_{d(off)}$			80		ns
Fall Time	t_f			70		ns
Total Gate Charge	Q_g	$V_{DS} = -15V, V_{GS} = -10V, I_D = -25A$		18.5		nC
Gate-to-Source Charge	Q_{gs}			3.2		nC
Gate-to-Drain "Miller" Charge	Q_{gd}			4.0		nC
Diode Forward Voltage	V_{SD}	$I_S = -25A, V_{GS} = 0V$		-0.99	-1.5	V

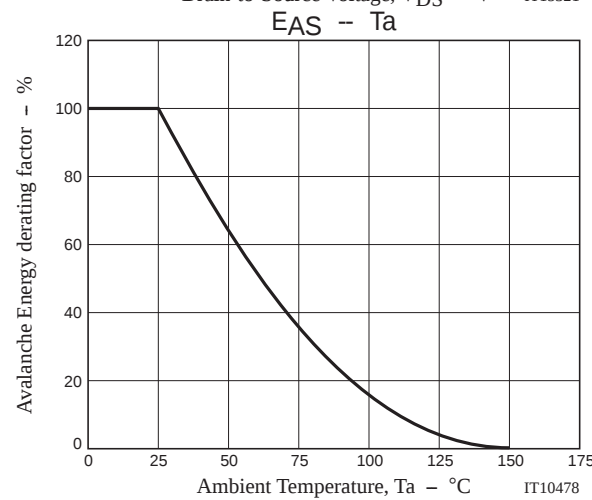
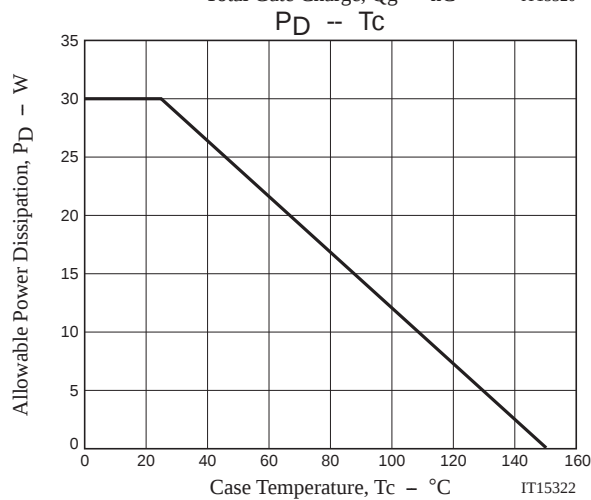
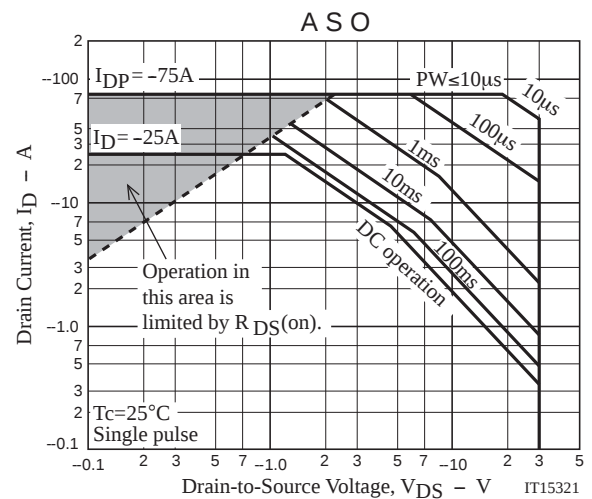
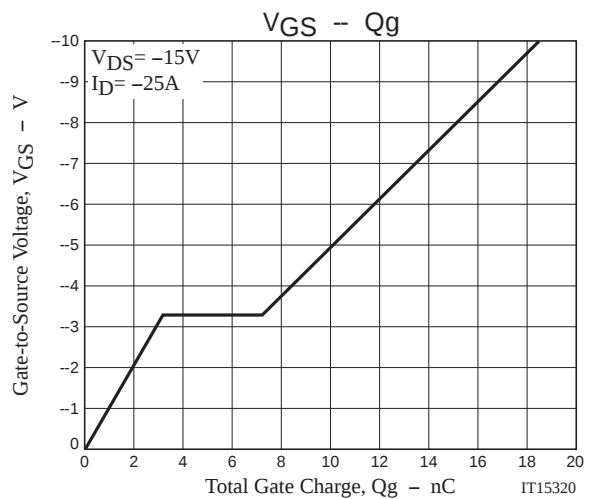
Switching Time Test Circuit



Ordering Information

Device	Package	Shipping	memo
ATP101-TL-H	ATPAK	3,000pcs./reel	Pb Free and Halogen Free



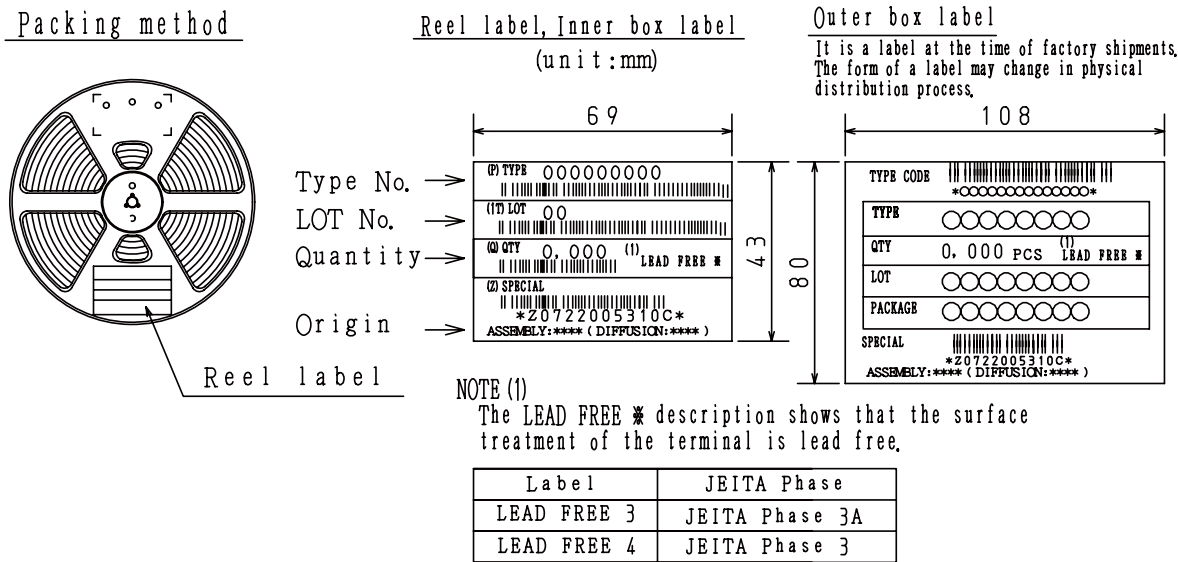


Taping Specification

ATP101-TL-H

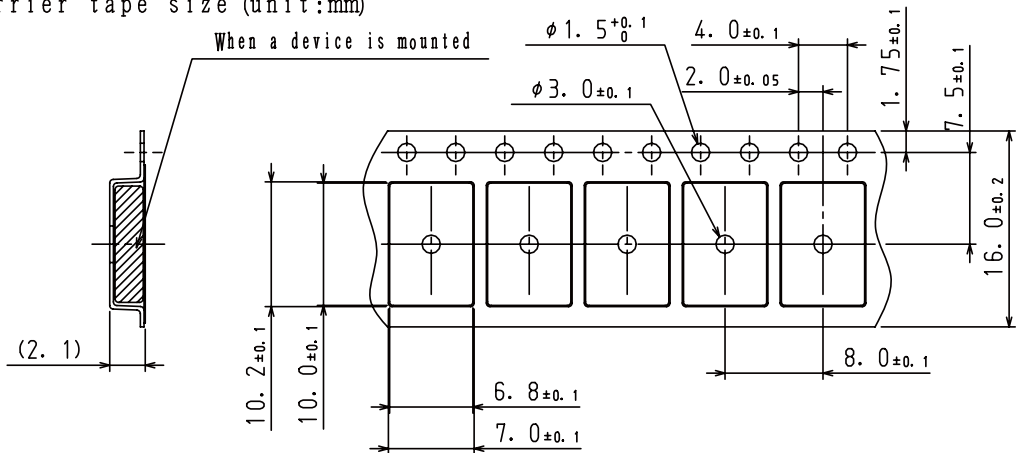
1. Packing Format (TL)

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	INNER BOX SD-C-18	OUTER BOX SD-A-18
ATPAK	ATP	3,000	3,000	15,000	1 reels contained Dimensions:mm (external) 340×340×28	5 inner boxes contained Dimensions:mm (external) 355×355×165

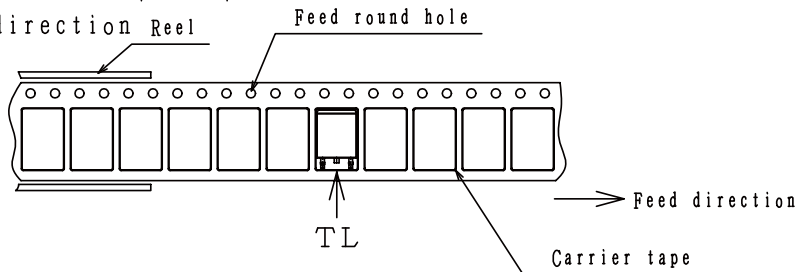


2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction Reel



The one electrode terminals on feed hole side...TL

Outline Drawing
ATP101-TL-H



Land Pattern Example



Note on usage : Since the ATP101 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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